Low-power buffer/line driver; 3-state Rev. 6 — 15 August 2012

Product data sheet

#### **General description** 1.

The 74AUP1G125 provides a single non-inverting buffer/line driver with 3-state output. The 3-state output is controlled by the output enable input (OE). A HIGH level at pin OE causes the output to assume a high-impedance OFF-state. This device has the input-disable feature, which allows floating input signals. The inputs are disabled when the output enable input OE) is HIGH.

Schmitt-trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire V<sub>CC</sub> range from 0.8 V to 3.6 V. This device ensures a very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using I<sub>OFF</sub>. The I<sub>OFF</sub> circuitry disables the output, preventing a damaging backflow current through the device when it is powered down.

#### Features and benefits 2.

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
  - JESD8-12 (0.8 V to 1.3 V)
  - ◆ JESD8-11 (0.9 V to 1.65 V)
  - JESD8-7 (1.2 V to 1.95 V)
  - JESD8-5 (1.8 V to 2.7 V)
  - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
  - HBM JESD22-A114F Class 3A exceeds 5000 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption;  $I_{CC} = 0.9 \mu A$  (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V<sub>CC</sub>
- Input-disable feature allows floating input conditions
- I<sub>OFF</sub> circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from –40 °C to +85 °C and –40 °C to +125 °C



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#### **Ordering information** 3.

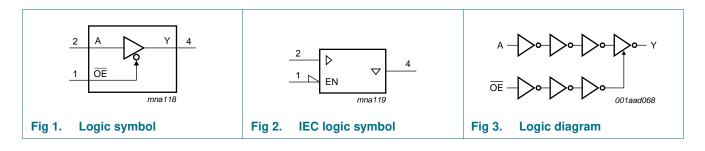
Table 1. Ordering	g information							
Type number	Package							
	Temperature range	Name	Description	Version				
74AUP1G125GW	–40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1				
74AUP1G125GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 $\times$ 1.45 $\times$ 0.5 mm	SOT886				
74AUP1G125GF	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 $\times$ 1 $\times$ 0.5 mm	SOT891				
74AUP1G125GN	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm	SOT1115				
74AUP1G125GS	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $1.0 \times 1.0 \times 0.35$ mm	SOT1202				
74AUP1G125GX	–40 °C to +125 °C	X2SON5	X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body $0.8 \times 0.8 \times 0.35$ mm	SOT1226				

#### Marking 4.

Table 2. Marking	
Type number	Marking code <sup>[1]</sup>
74AUP1G125GW	рМ
74AUP1G125GM	рМ
74AUP1G125GF	рМ
74AUP1G125GN	рМ
74AUP1G125GS	рМ
74AUP1G125GX	рМ

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

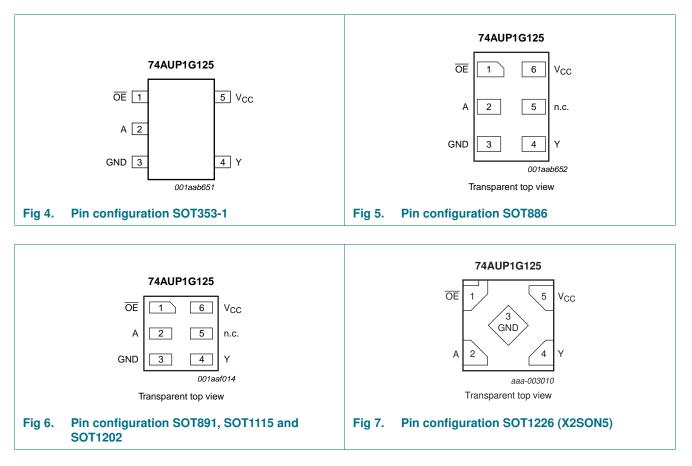
#### **Functional diagram** 5.



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#### **Pinning information** 6.

### 6.1 Pinning



### 6.2 Pin description

Table 3.	Pin des	scription		
Symbol		Pin		Description
		TSSOP5 and X2SON5	XSON6	
OE		1	1	output enable input
A		2	2	data input
GND		3	3	ground (0 V)
Y		4	4	data output
n.c.		-	5	not connected
V <sub>CC</sub>		5	6	supply voltage

### 7. Functional description

Input OE		Output
OE	Α	Y
L	L	L
L	Н	Н
Н	Х	Z

[1] H = HIGH voltage level;

L = LOW voltage level;

X = Don't care;

Z = high-impedance OFF-state.

### 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>1</sub> < 0 V	-50	-	mA
VI	input voltage		<u>[1]</u> –0.5	+4.6	V
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V	-50	-	mA
Vo	output voltage	Active mode	<u>[1]</u> –0.5	$V_{CC} + 0.5$	V
		Power-down mode	<u>[1]</u> –0.5	+4.6	V
l <sub>O</sub>	output current	$V_{O} = 0 V$ to $V_{CC}$	-	±20	mA
I <sub>CC</sub>	supply current		-	+50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40 \ ^{\circ}C \ to \ +125 \ ^{\circ}C$	[2]	250	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For TSSOP5 packages: above 87.5 °C the value of P<sub>tot</sub> derates linearly with 4.0 mW/K.
 For XSON6 and X2SON5 packages: above 118 °C the value of P<sub>tot</sub> derates linearly with 7.8 mW/K.

### 9. Recommended operating conditions

Table 6.	Recommended operating conditi	ons			
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V <sub>CC</sub>	V
		Power-down mode; $V_{CC} = 0 V$	0	3.6	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 0.8 \text{ V} \text{ to } 3.6 \text{ V}$	0	200	ns/V

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### **10. Static characteristics**

### Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 2	5 °C					
VIH	HIGH-level input voltage	$V_{CC} = 0.8 V$	$0.70\times V_{CC}$	-	-	V
		$V_{CC} = 0.9 V$ to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		$V_{CC}$ = 2.3 V to 2.7 V	1.6	-	-	V
		$V_{CC} = 3.0 V \text{ to } 3.6 V$	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_{CC} = 0.8 V$	-	-	$0.30 \times V_{CC}$	V
		$V_{CC} = 0.9 V$ to 1.95 V	-	-	$0.35 \times V_{CC}$	V
		$V_{CC}$ = 2.3 V to 2.7 V	-	-	0.7	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	0.9	V
V <sub>OH</sub>	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O}$ = –20 $\mu A;$ $V_{CC}$ = 0.8 V to 3.6 V	$V_{CC}-0.1$	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.75 \times V_{CC}$	-	-	V
		$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	1.11	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.32	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	2.05	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.9	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.72	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.6	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_O$ = 20 $\mu A;V_{CC}$ = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	$0.3\times V_{CC}$	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.31	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.31	V
		$I_{O} = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.31	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.44	V
		$I_{O} = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.31	V
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.44	V
l <sub>l</sub>	input leakage current	$V_I = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.1	μA
oz	OFF-state output current		-	-	±0.1	μA
OFF	power-off leakage current	$V_{I} \text{ or } V_{O}$ = 0 V to 3.6 V; $V_{CC}$ = 0 V	-	-	±0.2	μA
∆l <sub>OFF</sub>	additional power-off leakage current	$V_1$ or $V_O = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.2	μA
I <sub>CC</sub>	supply current	$\label{eq:VI} \begin{array}{l} V_{I}=GND \text{ or } V_{CC}; \ I_{O}=0 \ A; \\ V_{CC}=0.8 \ V \ to \ 3.6 \ V \end{array}$	-	-	0.5	μA

### Low-power buffer/line driver; 3-state

### Table 7. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
∆l <sub>CC</sub>	additional supply current	data input; V_I = V_{CC} - 0.6 V; I_O = 0 A; V_{CC} = 3.3 V	[1] -	-	40	μA
		$\label{eq:VCC} \overline{\text{OE}} \text{ input; } V_{\text{I}} = V_{\text{CC}} - 0.6 \text{ V; } I_{\text{O}} = 0 \text{ A;} \\ V_{\text{CC}} = 3.3 \text{ V}$	<u>[1]</u> -	-	110	μA
		all inputs; V <sub>I</sub> = GND to 3.6 V; $\overline{OE}$ = V <sub>CC</sub> ; V <sub>CC</sub> = 0.8 V to 3.6 V	[2] -	-	1	μA
Cı	input capacitance	$V_{CC}$ = 0 V to 3.6 V; $V_I$ = GND or $V_{CC}$	-	0.9	-	pF
Co	output capacitance					
	output enabled	$V_O = GND; V_{CC} = 0 V$	-	1.7	-	pF
	output disabled	$V_{CC}$ = 0 V to 3.6 V; $V_O$ = GND or $V_{CC}$	-	1.5	-	pF
T <sub>amb</sub> = –	40 °C to +85 °C					
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC} = 0.8 V$	$0.70 \times V_{CC}$	-	-	V
		$V_{CC} = 0.9 V$ to 1.95 V	$0.65 \times V_{CC}$	-	-	V
		$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$	1.6	-	-	V
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_{CC} = 0.8 V$	-	-	$0.30 \times V_{CC}$	V
		$V_{CC} = 0.9 V$ to 1.95 V	-	-	$0.35 \times V_{CC}$	V
		$V_{CC}$ = 2.3 V to 2.7 V	-	-	0.7	۷
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	0.9	۷
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{IH} \text{ or } V_{IL}$				
		$I_{O}$ = –20 $\mu A;$ $V_{CC}$ = 0.8 V to 3.6 V	$V_{CC}-0.1$	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$	$0.7\times V_{CC}$	-	-	٧
		$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$	1.03	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.30	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.97	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.85	-	-	٧
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.67	-	-	٧
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.55	-	-	٧
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_O$ = 20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.1	٧
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	$0.3\times V_{CC}$	٧
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.37	٧
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.35	V
		$I_{O} = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.33	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.45	V
		$I_{O} = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.33	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.45	V
1	input leakage current	$V_I = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.5	μA
oz	OFF-state output current		-	-	±0.5	μA
I <sub>OFF</sub>	power-off leakage current	$V_{I} \text{ or } V_{O}$ = 0 V to 3.6 V; $V_{CC}$ = 0 V	-	-	±0.5	μA
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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
∆I <sub>OFF</sub>	additional power-off leakage current	$      V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V};                                   $		-	-	±0.6	μA
CC	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = GND \text{ or } V_{CC};  I_{O} = 0 \; A; \\ V_{CC} = 0.8 \; V \; to \; 3.6 \; V \end{array}$		-	-	0.9	μA
Alcc	additional supply current	data input; V_I = V_{CC} - 0.6 V; I_O = 0 A; V_{CC} = 3.3 V	[1]	-	-	50	μA
		$\overline{\text{OE}}$ input; V <sub>I</sub> = V <sub>CC</sub> – 0.6 V; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 3.3 V	[1]	-	-	120	μA
		$\frac{\text{all inputs; V}_{\text{I}} = \text{GND to } 3.6 \text{ V;}}{\text{OE}} = \text{V}_{\text{CC}}; \text{V}_{\text{CC}} = 0.8 \text{ V to } 3.6 \text{ V}}$	<u>[2]</u>	-	-	1	μA
amb = -	40 °C to +125 °C						
/ <sub>IH</sub>	HIGH-level input voltage	$V_{CC} = 0.8 V$		$0.75 \times V_{CC}$	-	-	V
		$V_{CC} = 0.9 V$ to 1.95 V		$0.70 \times V_{CC}$	-	-	V
		$V_{CC}$ = 2.3 V to 2.7 V		1.6	-	-	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.0	-	-	V
/ <sub>IL</sub>	LOW-level input voltage	$V_{CC} = 0.8 V$		-	-	$0.25 \times V_{CC}$	V
		$V_{CC} = 0.9 V$ to 1.95 V		-	-	$0.30\times V_{CC}$	V
		$V_{CC}$ = 2.3 V to 2.7 V		-	-	0.7	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		-	-	0.9	V
/ <sub>ОН</sub> Н	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$					
		$I_O$ = –20 $\mu A;V_{CC}$ = 0.8 V to 3.6 V		$V_{CC}-0.11$	-	-	V
		$I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$		$0.6 \times V_{CC}$	-	-	V
		$I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$		0.93	-	-	V
		$I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$		1.17	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$		1.77	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$		1.67	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$		2.40	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$		2.30	-	-	V
/ <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$					
		$I_O$ = 20 $\mu A;V_{CC}$ = 0.8 V to 3.6 V		-	-	0.11	V
		$I_{O} = 1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$		-	-	$0.33 \times V_{CC}$	V
		$I_{O} = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$		-	-	0.41	V
		$I_{O} = 1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$		-	-	0.39	V
		$I_{O} = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$		-	-	0.36	V
		$I_{O} = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$		-	-	0.50	V
		$I_{O} = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$		-	-	0.36	V
		$I_{O} = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$		-	-	0.50	V
	input leakage current	$V_{I} = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V		-	-	±0.75	μA
OZ	OFF-state output current	$\label{eq:VI} \begin{array}{l} V_{I} = V_{IH} \text{ or } V_{IL};  V_{O} = 0   V \text{ to } 3.6   V; \\ V_{CC} = 0   V \text{ to } 3.6   V \end{array}$		-	-	±0.75	μA
OFF	power-off leakage current	$V_{I}$ or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V		-	-	±0.75	μA

### Table 7. Static characteristics ...continued

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#### Low-power buffer/line driver; 3-state

At recom	mended operating conditions	s; voltages are referenced to GND (grour	nd = 0 V).			
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$\Delta I_{OFF}$	additional power-off leakage current	$      V_1 \text{ or } V_O = 0 \text{ V to } 3.6 \text{ V}; \\       V_{CC} = 0 \text{ V to } 0.2 \text{ V} $	-	-	±0.75	μΑ
I <sub>CC</sub>	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = GND \text{ or } V_{CC}; \ I_{O} = 0 \ A; \\ V_{CC} = 0.8 \ V \ to \ 3.6 \ V \end{array}$	-	-	1.4	μΑ
$\Delta I_{CC}$	additional supply current	data input; V_I = V_{CC} - 0.6 V; I_O = 0 A; V_{CC} = 3.3 V	<u>[1]</u> _	-	75	μA
		$\overline{OE}$ input; V_I = V_{CC} - 0.6 V; I_O = 0 A; V_{CC} = 3.3 V	[1] -	-	180	μA
		all inputs; $V_1 = GND$ to 3.6 V; $\overline{OE} = V_{CC}$ ; $V_{CC} = 0.8$ V to 3.6 V	[2] _	-	1	μA

#### Table 7. Static characteristics ... continued

[1] One input at  $V_{CC}$  – 0.6 V, other input at  $V_{CC}$  or GND.

[2] To show  $I_{CC}$  remains very low when the input-disable feature is enabled.

### **11. Dynamic characteristics**

#### Table 8. **Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 10

Symbol	Parameter	Conditions		Min	Typ 🛄	Мах	Unit
T <sub>amb</sub> = 25	°C; C <sub>L</sub> = 5 pF						
t <sub>pd</sub>	propagation delay	A to Y; see Figure 8	[2]				
		$V_{CC} = 0.8 V$		-	20.6	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		2.8	5.5	10.5	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		2.2	3.9	6.1	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		1.9	3.2	4.8	ns
		$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$		1.6	2.6	3.6	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.4	2.4	3.1	ns
t <sub>en</sub>	enable time	OE to Y; see Figure 9	[3]				
		$V_{CC} = 0.8 V$		-	69.9	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.1	6.1	11.8	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		2.5	4.2	6.6	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		2.1	3.4	5.1	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.8	2.6	3.7	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.7	2.4	3.1	ns
t <sub>dis</sub>	disable time	OE to Y; see Figure 9	[4]				
		$V_{CC} = 0.8 V$		-	14.3	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		2.7	4.3	6.5	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		2.1	3.2	4.4	ns
		$V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$		2.0	3.0	4.3	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.4	2.2	2.9	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.7	2.5	3.2	ns

### Low-power buffer/line driver; 3-state

Symbol	Parameter	Conditions		Min	Typ 🛄	Мах	Unit
Г <sub>ать</sub> = 25	°C; C <sub>L</sub> = 10 pF						
pd	propagation delay	A to Y; see Figure 8	[2]				
		$V_{CC} = 0.8 V$		-	24.0	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.2	6.4	12.3	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		2.1	4.5	7.3	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		1.9	3.8	5.5	ns
		$V_{CC}$ = 2.3 V to 2.7 V		2.1	3.2	4.2	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.8	3.0	3.8	ns
en	enable time	OE to Y; see Figure 9	[3]				
		$V_{CC} = 0.8 V$		-	73.7	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V		3.6	6.9	13.5	ns
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		2.3	4.8	7.7	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		2.0	3.9	5.8	ns
		$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$		1.8	3.2	4.3	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.7	3.0	3.9	ns
dis	disable time	OE to Y; see Figure 9	[4]				
		V <sub>CC</sub> = 0.8 V		-	32.7	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V		3.4	5.4	7.9	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V		2.2	4.1	5.5	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		2.2	4.2	5.6	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.7	3.0	3.8	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V		2.1	3.8	4.8	ns
amb = 25	°C; C <sub>L</sub> = 15 pF						
pd	propagation delay	A to Y; see Figure 8	[2]				
1		$V_{CC} = 0.8 V$		-	27.4	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V		3.6	7.2	14.1	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V		3.0	5.1	8.1	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		2.2	4.3	6.3	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		2.0	3.7	4.9	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V		2.0	3.5	4.4	ns
en	enable time	OE to Y; see Figure 9	[3]				
		$V_{CC} = 0.8 V$		-	77.5	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V		4.0	7.7	15.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V		3.0	5.3	8.4	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		2.3	4.4	6.5	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V		2.1	3.6	5.0	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		2.0	3.5	4.5	ns

#### Table 8. Dynamic characteristics ... continued

Low-power buffer/line driver; 3-state

Symbol	Parameter	Conditions		Min	Typ 🛄	Мах	Unit
t <sub>dis</sub>	disable time	OE to Y; see Figure 9	[4]				
		$V_{CC} = 0.8 V$		-	60.8	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		4.3	6.5	9.2	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		3.0	5.0	6.5	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		3.0	5.3	6.6	ns
		$V_{CC}$ = 2.3 V to 2.7 V		2.1	3.8	4.9	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.9	5.0	6.2	ns
T <sub>amb</sub> = 25	°C; C <sub>L</sub> = 30 pF						
t <sub>pd</sub> propagation delay		A to Y; see Figure 8	[2]				
		$V_{CC} = 0.8 V$		-	37.4	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		4.8	9.5	19.0	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		4.0	6.7	10.8	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		2.9	5.6	8.4	ns
		$V_{CC}$ = 2.3 V to 2.7 V		2.7	4.8	6.3	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.7	4.6	5.8	ns
t <sub>en</sub>	enable time	OE to Y; see Figure 9	[3]				
		$V_{CC} = 0.8 V$		-	88.9	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		5.2	9.9	19.8	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		4.0	6.8	10.8	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		3.0	5.6	8.5	ns
		$V_{CC}$ = 2.3 V to 2.7 V		2.7	4.8	6.5	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.7	4.6	6.0	ns
t <sub>dis</sub>	disable time	OE to Y; see Figure 9	[4]				
		$V_{CC} = 0.8 V$		-	49.9	-	ns
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		6.0	9.9	13.3	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		4.4	7.7	9.6	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		5.1	8.7	11.1	ns
		$V_{CC}$ = 2.3 V to 2.7 V		3.6	6.2	7.4	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V		5.2	8.7	10.5	ns

#### Table 8. Dynamic characteristics ... continued

#### Low-power buffer/line driver; 3-state

Symbol	Parameter	Conditions		Min	Typ 🛄	Мах	Unit
T <sub>amb</sub> = 25	5 °C						
C <sub>PD</sub> power dissipation capacitance		f = 1 MHz; $V_I$ = GND to $V_{CC}$	[5]				
		output enabled					
	$V_{CC} = 0.8 V$		-	2.7	-	pF	
		V <sub>CC</sub> = 1.1 V to 1.3 V		-	2.8	-	pF
		V <sub>CC</sub> = 1.4 V to 1.6 V		-	2.9	-	pF
		V <sub>CC</sub> = 1.65 V to 1.95 V		-	3.0	-	pF
		$V_{CC}$ = 2.3 V to 2.7 V		-	3.6	-	pF
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		-	4.2	-	pF
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		-	4.2		-

#### Dynamic characteristics ... continued Table 8.

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[1] All typical values are measured at nominal V<sub>CC</sub>.

[2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

[3]  $t_{en}$  is the same as  $t_{PZH}$  and  $t_{PZL}$ .

[4]  $t_{dis}$  is the same as  $t_{PHZ}$  and  $t_{PLZ}$ .

[5]  $C_{PD}$  is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W).  $P_{D} = C_{PD} \times V_{CC}{}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}{}^{2} \times f_{o}) \text{ where:}$  $f_i$  = input frequency in MHz;  $f_o = output frequency in MHz;$  $C_L$  = output load capacitance in pF; V<sub>CC</sub> = supply voltage in V; N = number of inputs switching;  $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

#### Table 9. **Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 10

Symbol	Parameter	Conditions		–40 °C to +85 °C		–40 °C to	Unit	
				Min	Max	Min	Max	
C <sub>L</sub> = 5 pF								
t <sub>pd</sub>	propagation delay	A to Y; see Figure 8	<u>[1]</u>					
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		2.5	11.7	2.5	12.9	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		2.0	7.3	2.0	8.1	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		1.7	6.1	1.7	6.7	ns
		$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$		1.4	4.3	1.4	4.9	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.2	3.9	1.2	4.4	ns
t <sub>en</sub>	enable time	OE to Y; see Figure 9	[2]					
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		2.9	13.9	2.9	15.4	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		2.3	7.7	2.3	8.3	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		2.0	6.2	2.0	6.8	ns
		$V_{CC}$ = 2.3 V to 2.7 V		1.7	4.5	1.7	5.0	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.7	3.5	1.7	3.9	ns

### Low-power buffer/line driver; 3-state

Symbol Parameter		Conditions		–40 °C to +85 °C		-40 °C to +125 °C		Unit	
				Min	Max	Min	Max		
dis	disable time	OE to Y; see Figure 9	[3]						
		$V_{CC} = 1.1 \text{ V}$ to 1.3 V		2.7	7.3	2.7	8.2	ns	
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		2.1	5.1	2.1	5.7	ns	
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		2.0	5.0	2.0	5.7	ns	
		$V_{CC}$ = 2.3 V to 2.7 V		1.4	3.3	1.4	4.1	ns	
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.7	3.4	1.7	3.9	ns	
C <sub>L</sub> = 10 p	F								
pd	propagation delay	A to Y; see Figure 8	[1]						
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.0	13.8	3.0	15.2	ns	
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		1.9	8.5	1.9	9.4	ns	
		V <sub>CC</sub> = 1.65 V to 1.95 V		1.7	6.8	1.7	7.6	ns	
		$V_{CC}$ = 2.3 V to 2.7 V		1.6	5.3	1.6	5.9	ns	
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.6	4.6	1.6	5.2	ns	
en	enable time	OE to Y; see Figure 9	[2]						
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.4	15.8	3.4	17.5	ns	
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		2.2	8.6	2.2	9.4	ns	
		V <sub>CC</sub> = 1.65 V to 1.95 V		1.9	6.8	1.9	7.4	ns	
		$V_{CC}$ = 2.3 V to 2.7 V		1.7	5.3	1.7	5.9	ns	
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.7	4.3	1.7	4.8	ns	
dis	disable time	OE to Y; see Figure 9	[3]						
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.4	8.8	3.4	9.9	ns	
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		2.2	6.2	2.2	7.1	ns	
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		1.9	6.3	1.9	7.1	ns	
		$V_{CC}$ = 2.3 V to 2.7 V		1.7	4.5	1.7	5.1	ns	
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.7	5.0	1.7	5.6	ns	
C <sub>L</sub> = 15 p	F								
pd	propagation delay	A to Y; see Figure 8	<u>[1]</u>						
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.3	15.8	3.3	17.5	ns	
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$		2.5	9.8	2.5	10.9	ns	
		V <sub>CC</sub> = 1.65 V to 1.95 V		2.0	7.9	2.0	8.8	ns	
		$V_{CC}$ = 2.3 V to 2.7 V		1.8	6.0	1.8	6.7	ns	
		$V_{CC}$ = 3.0 V to 3.6 V		1.8	5.4	1.8	6.1	ns	
en	enable time	OE to Y; see Figure 9	[2]						
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.7	17.6	3.7	19.6	ns	
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		2.5	9.8	2.5	10.7	ns	
		$V_{CC}$ = 1.65 V to 1.95 V		2.1	7.7	2.1	8.5	ns	
		$V_{CC}$ = 2.3 V to 2.7 V		2.0	6.1	2.0	6.8	ns	
		$V_{CC} = 3.0 \text{ V}$ to 3.6 V		1.9	4.9	1.9	5.5	ns	

#### Table 9. Dynamic characteristics ... continued

### Low-power buffer/line driver; 3-state

Symbol	Parameter	Conditions		–40 °C i	to +85 °C	–40 °C to	Unit	
				Min	Max	Min	Max	
dis	disable time	OE to Y; see Figure 9	[3]					
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		3.7	10.3	3.7	11.6	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		2.5	7.4	2.5	8.4	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		2.1	7.4	2.1	8.9	ns
		$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$		2.0	5.1	2.0	6.4	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		1.9	6.6	1.9	7.4	ns
C <sub>L</sub> = 30 p	F							
t <sub>pd</sub> propagation delay		A to Y; see Figure 8	[1]					
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		4.4	21.6	4.4	24.0	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		3.0	13.0	3.0	14.5	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		2.6	10.3	2.6	11.5	ns
		$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$		2.5	7.8	2.5	8.7	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.5	7.5	2.5	8.3	ns
en	enable time	OE to Y; see Figure 9	[2]					
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		4.8	22.8	4.8	25.3	ns
		$V_{CC} = 1.4 \text{ V}$ to 1.6 V		3.1	12.6	3.1	14.1	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		2.8	10.2	2.8	11.3	ns
		$V_{CC}$ = 2.3 V to 2.7 V		2.6	7.8	2.6	8.8	ns
		$V_{CC} = 3.0 V \text{ to } 3.6 V$		2.6	6.9	2.6	7.7	ns
dis	disable time	OE to Y; see Figure 9	[3]					
		$V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$		4.8	14.8	4.8	16.5	ns
		$V_{CC} = 1.4 V \text{ to } 1.6 V$		3.1	10.7	3.1	12.1	ns
		$V_{CC} = 1.65 \text{ V}$ to 1.95 V		2.8	12.4	2.8	13.8	ns
		$V_{CC}$ = 2.3 V to 2.7 V		2.6	8.6	2.6	9.6	ns
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		2.6	10.8	2.6	13.1	ns

### Table 9. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 10

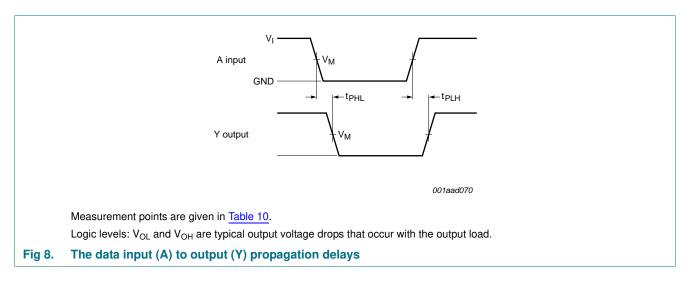
[1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

[2]  $t_{en}$  is the same as  $t_{PZH}$  and  $t_{PZL}$ .

[3]  $t_{dis}$  is the same as  $t_{PHZ}$  and  $t_{PLZ}$ .

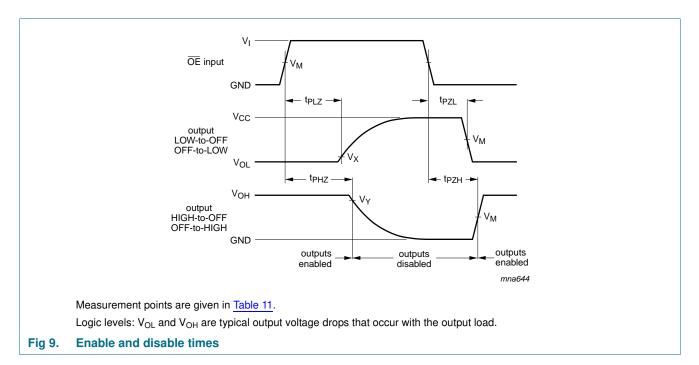
#### Low-power buffer/line driver; 3-state

### 12. Waveforms



### Table 10. Measurement points

Supply voltage	Output	Input				
V <sub>CC</sub>	V <sub>M</sub>	V <sub>M</sub>	VI	t <sub>r</sub> = t <sub>f</sub>		
0.8 V to 3.6 V	$0.5  imes V_{CC}$	$0.5  imes V_{CC}$	V <sub>CC</sub>	$\leq$ 3.0 ns		

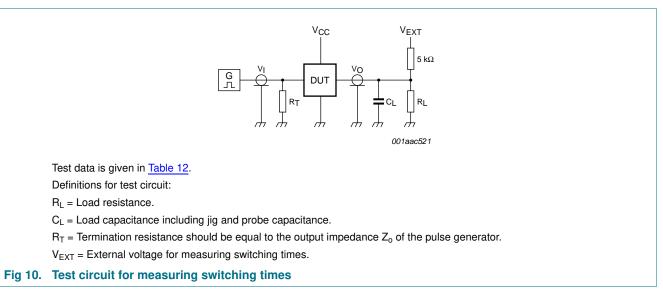


### **NXP Semiconductors**

# 74AUP1G125

### Low-power buffer/line driver; 3-state

Table 11. Measurement points							
Supply voltage	Input	Output					
V <sub>CC</sub>	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>			
0.8 V to 1.6 V	$0.5\times V_{CC}$	$0.5 \times V_{CC}$	$V_{OL}$ + 0.1 V	V <sub>OH</sub> – 0.1 V			
1.65 V to 2.7 V	$0.5\times V_{CC}$	$0.5\times V_{CC}$	$V_{OL} + 0.15 \ V$	V <sub>OH</sub> – 0.15 V			
3.0 V to 3.6 V	$0.5\times V_{CC}$	$0.5\times V_{CC}$	$V_{OL} + 0.3 V$	V <sub>OH</sub> – 0.3 V			



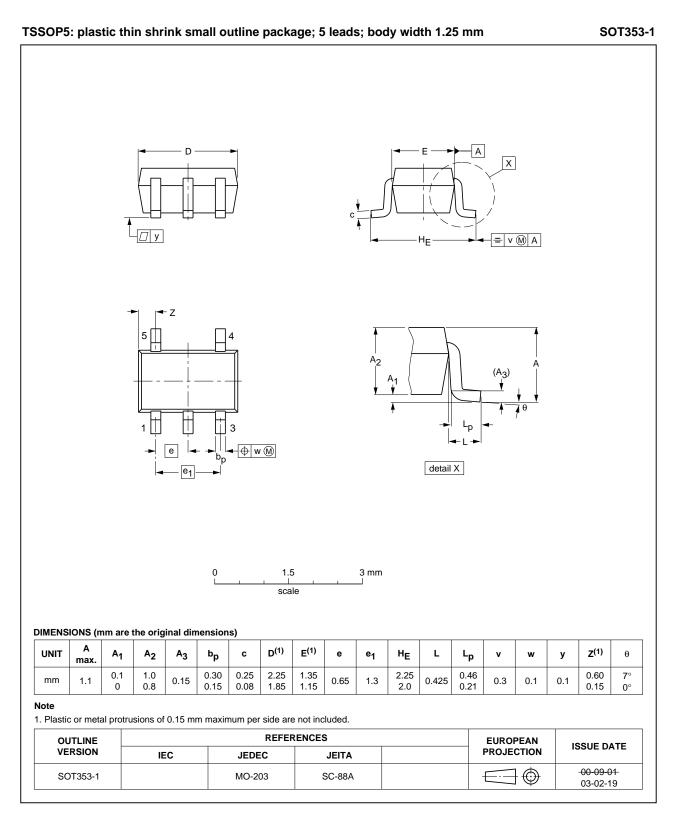
#### Table 12. Test data

Supply voltage	Load		V <sub>EXT</sub>			
V <sub>cc</sub>	CL	R <sub>L</sub> [1]	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>	
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	$5 \text{ k}\Omega$ or $1 \text{ M}\Omega$	open	GND	$2 \times V_{CC}$	

[1] For measuring enable and disable times  $R_L = 5 \text{ k}\Omega$ , for measuring propagation delays, setup and hold times and pulse width  $R_L = 1 \text{ M}\Omega$ .

Low-power buffer/line driver; 3-state

### 13. Package outline



#### Fig 11. Package outline SOT353-1 (TSSOP5)

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Low-power buffer/line driver; 3-state

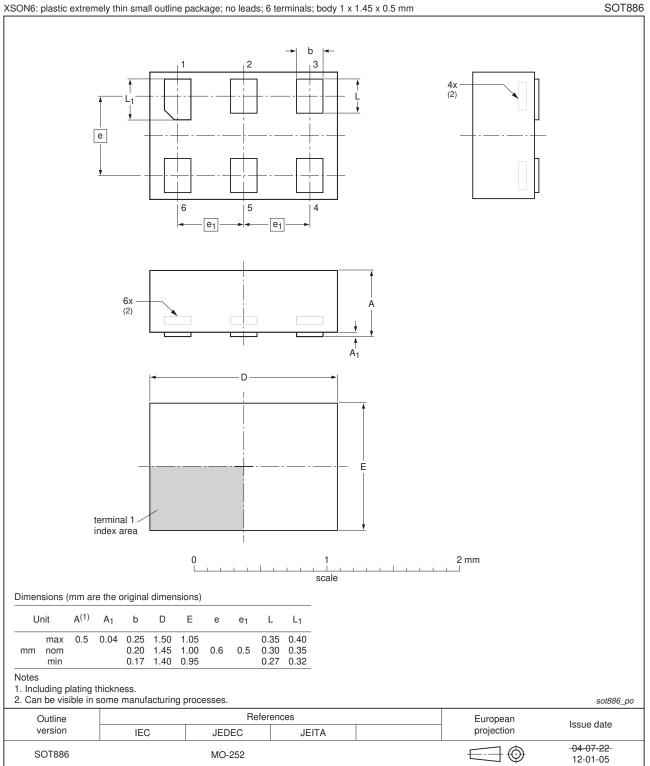
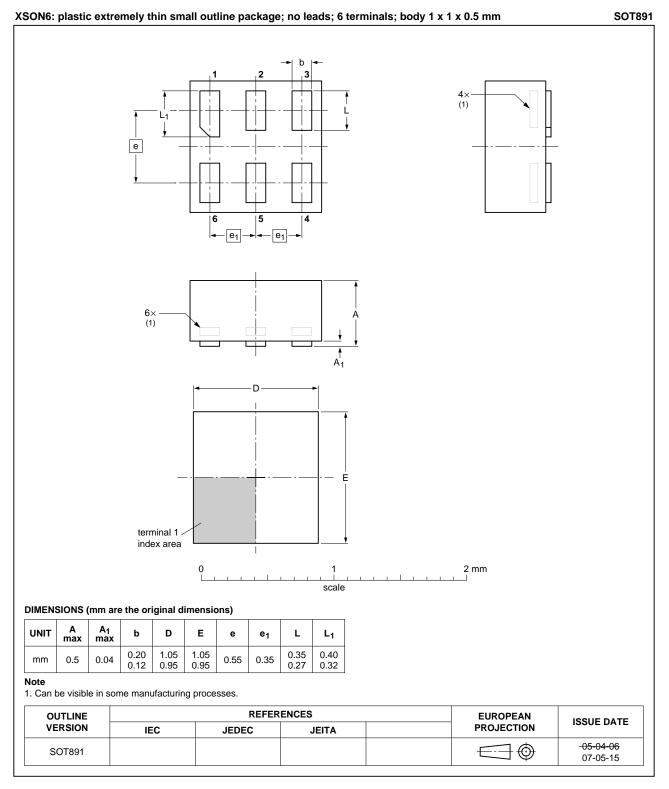


Fig 12. Package outline SOT886 (XSON6)

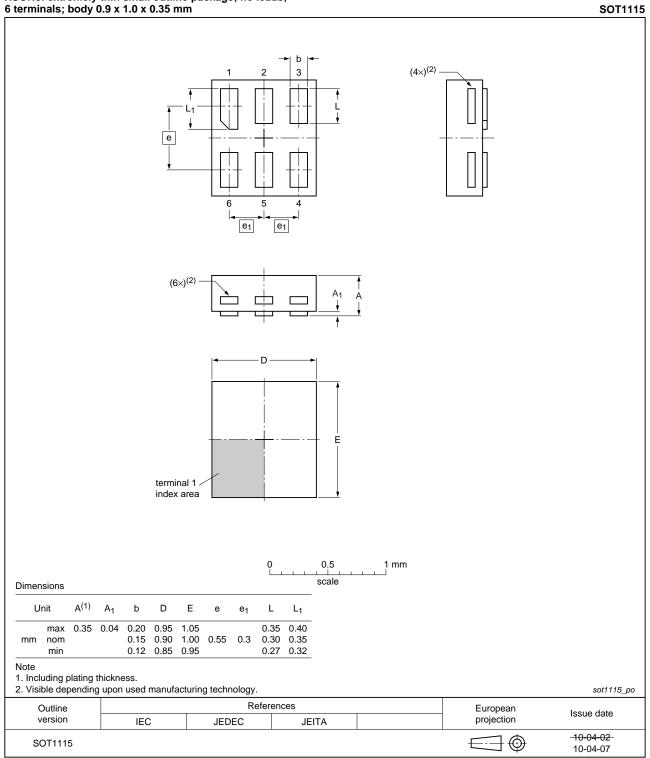
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Low-power buffer/line driver; 3-state



#### Fig 13. Package outline SOT891 (XSON6)

Low-power buffer/line driver; 3-state



### XSON6: extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm

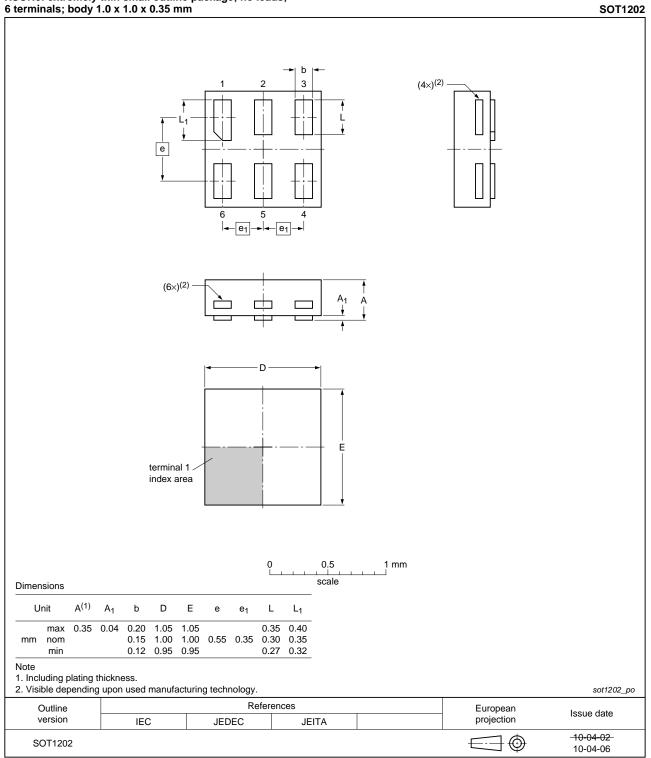
Fig 14. Package outline SOT1115 (XSON6)

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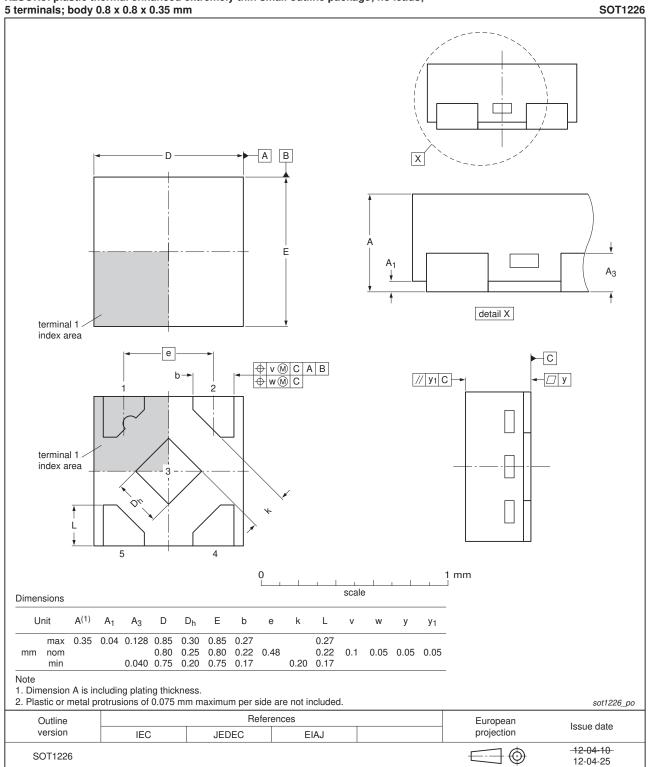


XSON6: extremely thin small outline package; no leads; 6 terminals; body 1.0 x 1.0 x 0.35 mm

Fig 15. Package outline SOT1202 (XSON6)

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### X2SON5: plastic thermal enhanced extremely thin small outline package; no leads;

Fig 16. Package outline SOT1226 (X2SON5)

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### 14. Abbreviations

Table 13. Abb	Table 13. Abbreviations					
Acronym	Description					
CDM	Charged Device Model					
DUT	Device Under Test					
ESD	ElectroStatic Discharge					
HBM	Human Body Model					
MM	Machine Model					

### **15. Revision history**

#### Table 14. Revision history **Document ID Release date** Data sheet status Change notice Supersedes 74AUP1G125 v.6 20120815 Product data sheet 74AUP1G125 v.5 \_ Modifications: • Errata in general description corrected 74AUP1G125 v.5 20120731 Product data sheet 74AUP1G125 v.4 -Modifications: Added type number 74AUP1G125GX (SOT1226) • Package outline drawing of SOT886 (Figure 12) modified. 74AUP1G125 v.4 74AUP1G125 v.3 20111129 Product data sheet -74AUP1G125 v.3 20100901 Product data sheet 74AUP1G125 v.2 \_ 74AUP1G125 v.2 Product data sheet 74AUP1G125 v.1 20060630 \_ 74AUP1G125 v.1 Product data sheet 20050718 --

### 16. Legal information

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Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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